

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

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ATP304

ON Semiconductor®

P-Channel Power MOSFET -60V, -100A, 6.5mΩ, ATPAK

http://onsemi.com

Features

- On-resistance $R_{DS}(on)1=5.0m\Omega(typ.)$
- Input Capacitance Ciss=13000pF(typ.)
- 4.5V drive
- Halogen Free compliance

Specifications

Absolute Maximum Ratings at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
Drain to Source Voltage	V _{DSS}		-60	٧
Gate to Source Voltage	V _{GSS}		±20	٧
Drain Current (DC)	ID		-100	Α
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	-400	Α
Allowable Power Dissipation	PD	Tc=25°C	90	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		- 55 to +150	°C
Avalanche Energy (Single Pulse) *1	EAS		656	mJ
Avalanche Current *2	IAV		-75	Α

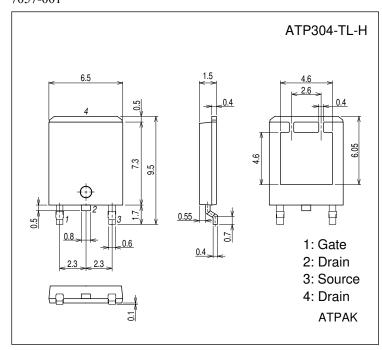
Note: *1 V_{DD} =-36V, L=100 μH , I_{AV} =-75A

*2 L≤100µH, Single pulse

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Package Dimensions

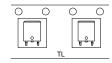
unit : mm (typ) 7057-001



Ordering & Package Information

Device	Package	Shipping	note	
ATP304-TL-H	ATPAK	3,000 pcs. / reel	Pb-Free	
			and Halogen-Free	

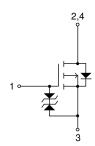
Packing Type: TL



Marking



Electrical Connection



Electrical Characteristics at $Ta = 25^{\circ}C$

Parameter	0	Conditions		Ratings		
	Symbol		min	typ	max	Unit
Drain to Source Breakdown Voltage	V(BR)DSS	I _D =-1mA, V _G S=0V	-60			٧
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =-60V, V _{GS} =0V			-10	μΑ
Gate to Source Leakage Current	IGSS	V _{GS} =±16V, V _{DS} =0V			±10	μΑ
Cutoff Voltage	V _{GS} (off)	V _{DS} =-10V, I _D =-1mA	-1.2		-2.6	٧
Forward Transfer Admittance	yfs	V _{DS} =-10V, I _D =-50A		100		S
Static Drain to Source On-State Resistance	R _{DS} (on)1	I _D =-50A, V _{GS} =-10V		5.0	6.5	mΩ
	R _{DS} (on)2	I _D =-50A, V _G S=-4.5V		6.4	8.9	mΩ
Input Capacitance	Ciss			13000		pF
Output Capacitance	Coss	V _{DS} =-20V, f=1MHz		1080		pF
Reverse Transfer Capacitance	Crss	1		760		pF
Turn-ON Delay Time	t _d (on)	See Fig.2		80		ns
Rise Time	t _r			650		ns
Turn-OFF Delay Time	t _d (off)			780		ns
Fall Time	tf			460		ns
Total Gate Charge	Qg			250		nC
Gate to Source Charge	Qgs	V _{DS} =-36V, V _{GS} =-10V, I _D =-100A		55		nC
Gate to Drain "Miller" Charge	Qgd	7		50		nC
Diode Forward Voltage	V _{SD}	I _S =-100A, V _{GS} =0V		-1.0	-1.5	٧
Reverse Recoverry Time	t _{rr}	See Fig.3		90		ns
Reverse Recoverry Charge	Q _{rr}	I _S =-100A, V _{GS} = 0V, di/dt=100A/μs		245		nC

Fig.1 Unclamped Inductive Switching Test Circuit

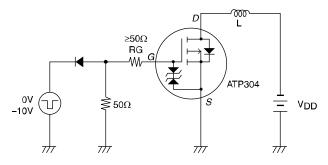


Fig.2 Switching Time Test Circuit

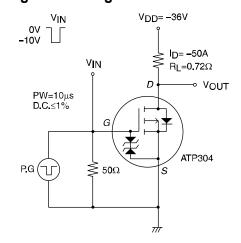
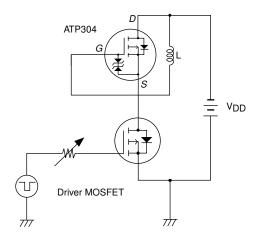
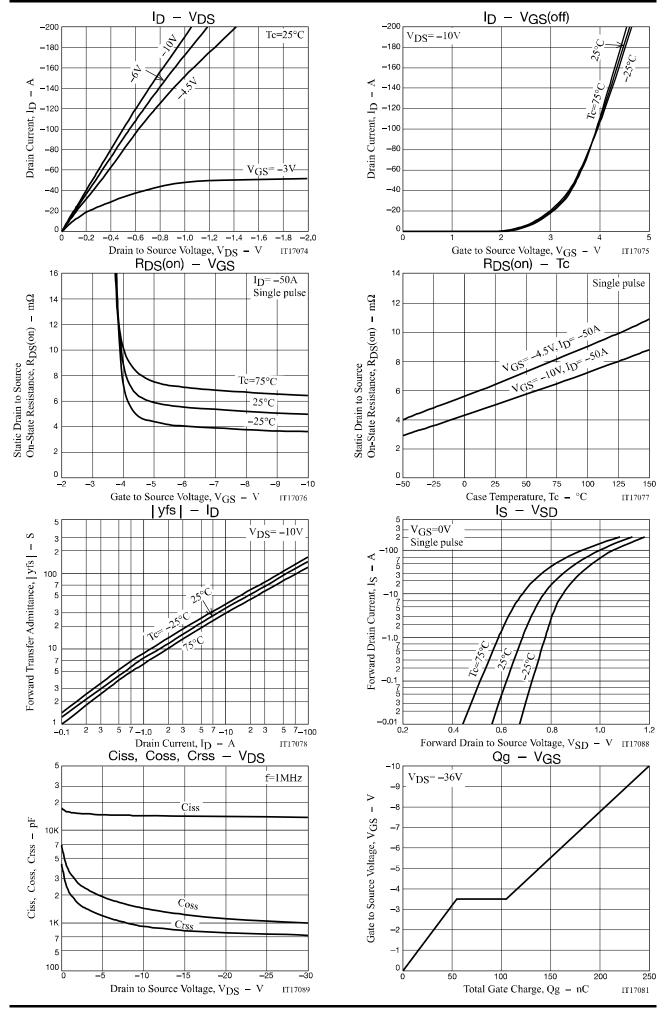
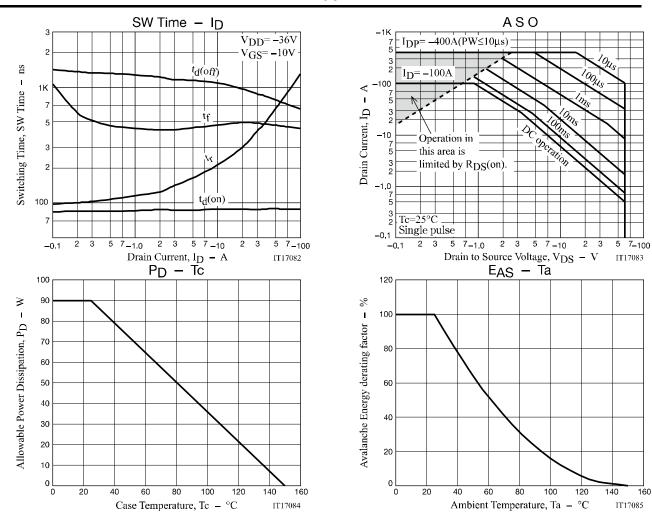


Fig.3 Reverse Recovery Time Test Circuit







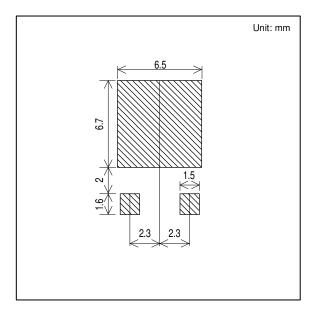
160

Outline Drawing

ATP304-TL-H

Mass (g) Unit 0.266 For reference mm 6.540 15

Land Pattern Example



Note on usage: Since the ATP304 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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